





MSD02120G1 1200V Silicon Carbide Diode

Features

- -1200-Volt Schottky Rectifier
- -Shorter recovery time
- -High-speed switching possible
- -High-Frequency Operation
- -Temperature-Independent Switching Behavior
- -Extremely Fast Switching
- -Positive Temperature Coefficient on VF

Benefits

Package

- -Higher safety margin against overvoltage
- -Improved efficiency all load conditions
- -Increased efficiency compared to Silicon Diode alternatives
- -Reduction of Heat Sink Requirements
- -Parallel Devices Without Thermal Runaway
- -Essentialy No Switching Losses

Applications

- -Switch Mode Power Supplies
- -Power Factor Correction
- -Motor Drives
- -HID Lighting





Type: TO-252(D-PAK)

Absolute Maximum Ratings

 T_C = 25° C unless otherwise noted

Symbol	Parameter	MSD02120G1	Units
VRRM	Repetitive Peak Reverse Voltage	1200	V
VRSM	Surge Peak Reverse Voltage	1200	٧
VDC	DC Blocking Voltage	1200	V
IF	Continuous Forward Current @Tc=25°C @Tc=125°C @Tc=150°C	9.5 5 2	А
IFRM	Repetitive Peak Forward Surge Current @TC=25°C, tp = 10 ms, Half Sine Wave	10	А
IFSM	Non-Repetitive Peak Forward Surge Current @TC=25°C, tp = 10 ms, Half Sine Wave	18	А
IF.MAX	Non-Repetitive Peak Forward Surge Current @TC=25℃, tp = 10 us, Plus	180	А
Ptot	Power Dissipation @Tc=25°C @Tc=110°C	76.5 33.2	W
TJ , Tstg	Operating Junction and Storage Temperature	-55 to +175	°C

Package Marking

Part Number	Top Marking	Package	Packing Method	MOQ	QTY
MSD02120G1	MSD02120G1	T0-252	Tape & Reel	2500	25000

Electrical Characteristics T_c = 25° C unless otherwise noted

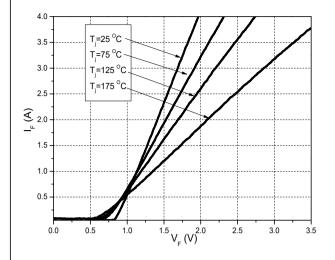
Symbol	Test Conditions	Test Conditions	Min	Тур	Max	Unit
VF	Forward Voltage	IF=2A, TC=25° C IF=2A, TC=175° C	-	1.4 2.1	1.8 2.5	V
IR	Reverse Current	VR=1200V, TC=25° C VR=1200V, TC=175° C	-	2 40	20 100	μΑ
QC	Total Capacitive Charge	VR =800V, IF =2A TJ = 25° C Qc= $\int_{0}^{\nu_{r}} C (V) dv$	-	11.2	-	nC
С	Total Capacitance	VR =0V, TJ = 25° C, f=1MHz VR =400V, TJ = 25° C, f=1MHz VR =800V, TJ = 25° C, f=1MHz	-	148 11 8		pF
EC	Capacitance Stored Energy	VR=800V	-	5.8	-	μJ

Thermal Characteristics

Symbol	Parameter		Unit
RθJC	Thermal Resistance from Junction to Case	1.96	°C/W

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Typical Characteristics





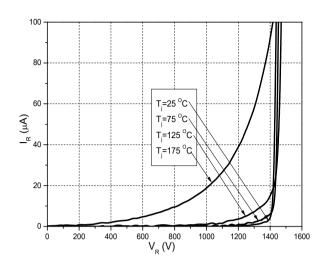


Figure 2. Reverse Characteristics

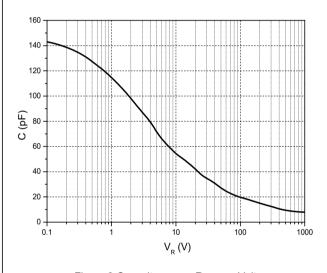


Figure 3.Capacitance vs. Reverse Voltage

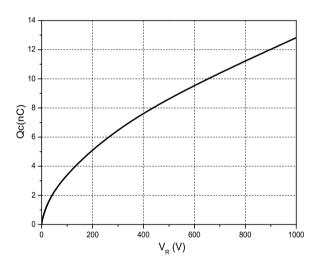


Figure 4. Total Capacitance Charge vs. Reverse Voltage

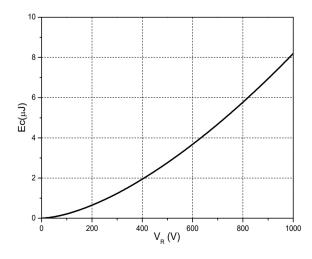


Figure 5. Capacitance Stored Energy

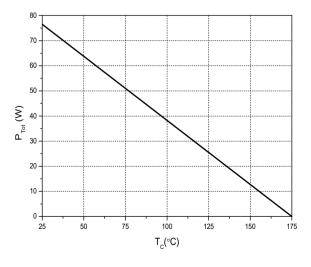
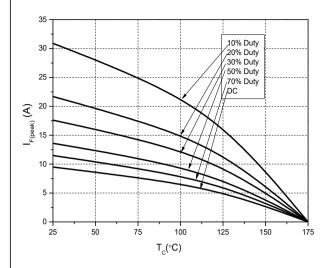


Figure 6. Power Derating

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Typical Characteristics



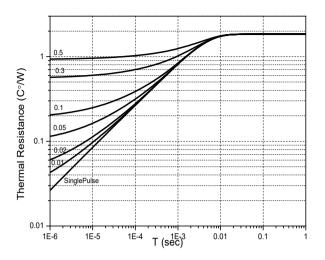
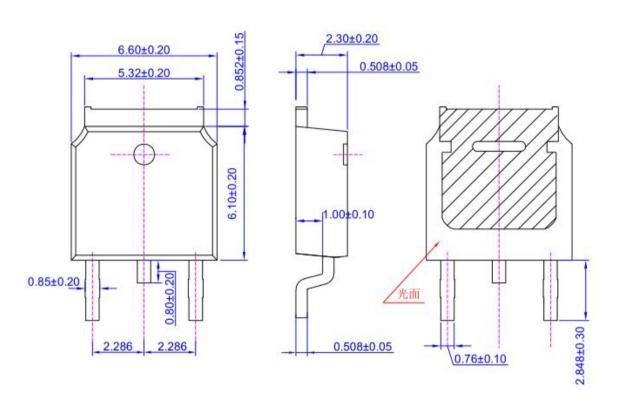


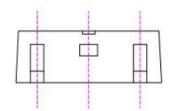
Figure 7. Current Derating

Figure 8. Transient Thermal Impedance

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TO-252 OUTLINE





NOTE:

1The plastic package is not marked as smooth surfaceRa=0.1;Subglossy surfaceRa=0.8 2.Undeclared tolerance \pm 0.25,Unmarked filletRmax=0.25

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